





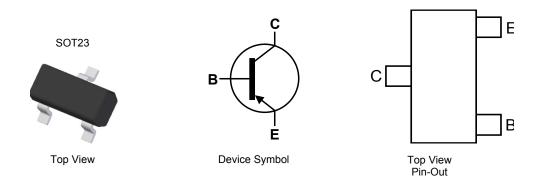
#### 30V PNP MEDIUM POWER HIGH PERFORMANCE TRANSISTOR IN SOT23

#### **Features**

- BV<sub>CEO</sub> > -30V
- I<sub>C</sub> = -1A Continuous Collector Current
- I<sub>CM</sub> = -2A Peak Pulse Current
- Low saturation voltage V<sub>CE(sat)</sub> < -350mV @ -1A</li>
- R<sub>SAT</sub> = 250mΩ for a low equivalent on-resistance
- Complementary NPN type: FMMT489
- Totally Lead-Free & Fully RoHS compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q101 Standards for High Reliability

#### **Mechanical Data**

- Case: SOT23
- Case Material: molded plastic, "Green" molding compound UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Matte Tin Plated Leads, Solderable per MIL-STD-202, Method 208 @3
- Weight: 0.008 grams (approximate)



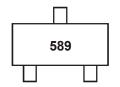
### Ordering Information (Note 4)

Product	Marking	Reel size (inches)	Tape width (mm)	Quantity per reel
FMMT589TA	589	7	8	3,000

Notes:

- 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant.
- 2. See http://www.diodes.com/quality/lead\_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Halogen and Antimony free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 4. For packaging details, go to our website at http://www.diodes.com/products/packages.html.

### **Marking Information**



589 = Product Type Marking Code



### Absolute Maximum Ratings (@TA = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Collector-Base Voltage	V <sub>CBO</sub>	-50	V
Collector-Emitter Voltage	V <sub>CEO</sub>	-30	V
Emitter-Base Voltage	V <sub>EBO</sub>	-7	V
Continuous Collector Current	Ic	-1	Α
Peak Pulse Current	I <sub>CM</sub>	-2	Α
Base Current	I <sub>B</sub>	-200	mA

### **Thermal Characteristics** (@ $T_A$ = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit	
Power Dissipation	(Note 5)	$P_{D}$	500	mW
Thermal Resistance, Junction to Ambient (N		$R_{\theta JA}$	250	°C/W
Thermal Resistance, Junction to Lead (Note 6)		$R_{ heta JL}$	197	°C/W
Operating and Storage Temperature Range		T <sub>J</sub> , T <sub>STG</sub>	-55 to +150	°C

### ESD Ratings (Note 7)

Characteristic	Symbol	Value	Unit	JEDEC Class
Electrostatic Discharge - Human Body Model	ESD HBM	4,000	V	3A
Electrostatic Discharge - Machine Model	ESD MM	400	V	С

Notes:

<sup>5.</sup> For a device mounted with the collector lead on 15mm x 15mm 1oz copper that is on a single-sided FR4 PCB; device is measured under still air conditions whilst operating in a steady-state.

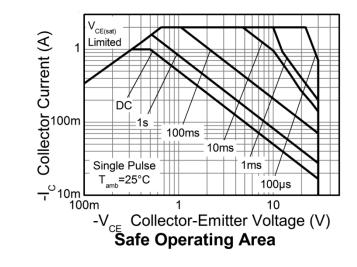
6. Thermal resistance from junction to solder-point (at the end of the collector lead).

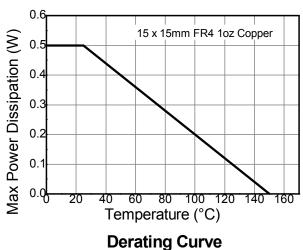
7. Refer to JEDEC specification JESD22-A114 and JESD22-A115.

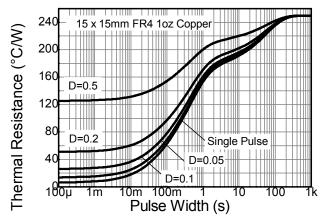


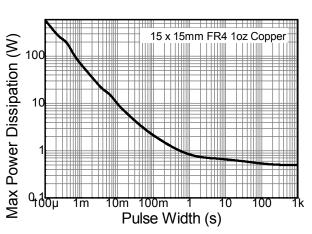


### **Thermal Characteristics and Derating Information**









**Transient Thermal Impedance** 

**Pulse Power Dissipation** 



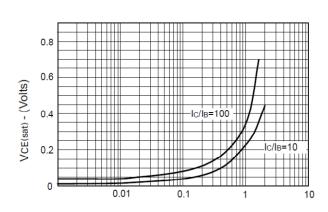
### Electrical Characteristics (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition
OFF CHARACTERISTICS						
Collector-Base Breakdown Voltage	BV <sub>CBO</sub>	-50	_	_	V	I <sub>C</sub> = -100μA
Collector-Emitter Breakdown Voltage (Note 8)	BV <sub>CEO</sub>	-30	_	_	V	I <sub>C</sub> = -10mA
Emitter-Base Breakdown Voltage	BV <sub>EBO</sub>	-7	_	_	V	I <sub>E</sub> = -100μA
Collector Cutoff Current	I <sub>CBO</sub>	_	_	-100	nA	V <sub>CB</sub> = -30V
Collector-Emitter Cutoff Current	I <sub>CES</sub>	_	_	-100	nA	V <sub>CES</sub> = -30V
Emitter Cutoff Current	I <sub>EBO</sub>	_	_	-100	nA	V <sub>EB</sub> = -5.6V
ON CHARACTERISTICS (Note 8)						
DC Current Gain	h <sub>FE</sub>	100 100 80 40	_ _ _ _	300 — —	_	$I_{C}$ = -1mA, $V_{CE}$ = -2V $I_{C}$ = -500mA, $V_{CE}$ = -2V $I_{C}$ = -1A, $V_{CE}$ = -2V $I_{C}$ = -2A, $V_{CE}$ = -2V
Collector-Emitter Saturation Voltage	V <sub>CE(sat)</sub>	_ 	_ _ _	-0.25 -0.35 -0.65	V	$I_C = -0.5A$ , $I_B = -50mA$ $I_C = -1A$ , $I_B = -100mA$ $I_C = -2A$ , $I_B = -200mA$
Base-Emitter Saturation Voltage	V <sub>BE(sat)</sub>	_	_	-1.2	V	I <sub>C</sub> = -1A, I <sub>B</sub> = -100mA
Base-Emitter Turn-On Voltage	V <sub>BE(on)</sub>	_	_	-1.1	V	I <sub>C</sub> = -1A, V <sub>CE</sub> = -2V
SMALL SIGNAL CHARACTERISTICS						
Output Capacitance	C <sub>obo</sub>	_	_	15	pF	V <sub>CB</sub> = -10V, f = 1MHz
Current Gain-Bandwidth Product	f⊤	100	_	_	MHz	V <sub>CE</sub> = -5V, I <sub>C</sub> = -100mA, f = 100MHz

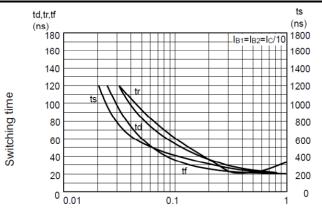
Notes: 8. Measured under pulsed conditions. Pulse width  $\leq 300 \mu s.$  Duty cycle  $\leq 2\%$ 



### Typical Electrical Characteristics (@T<sub>A</sub> = +25°C, unless otherwise specified.)



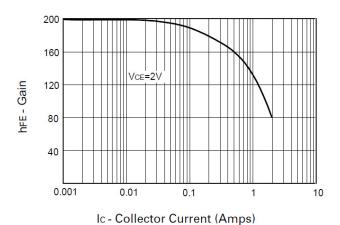
Ic - Collector Current (Amps)



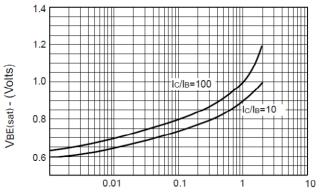
Ic - Collector Current (Amps)

**Switching Speeds** 

#### VCE(sat) v IC

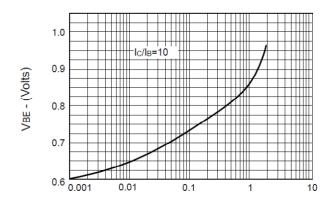


hFE v IC



Ic - Collector Current (Amps)

#### VBE(sat) v IC



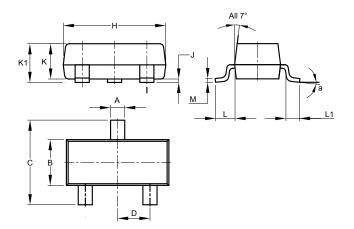
Ic - Collector Current (Amps)

#### VBE(on) v IC



### **Package Outline Dimensions**

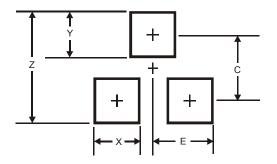
Please see AP02002 at http://www.diodes.com/datasheets/ap02002.pdf for latest version.



SOT23					
Dim	Min	Max	Тур		
Α	0.37	0.51	0.40		
В	1.20	1.40	1.30		
С	2.30	2.50	2.40		
D	0.89	1.03	0.915		
F	0.45	0.60	0.535		
G	1.78	2.05	1.83		
Н	2.80	3.00	2.90		
J	0.013	0.10	0.05		
K	0.890	1.00	0.975		
K1	0.903	1.10	1.025		
L	0.45	0.61	0.55		
L1	0.25	0.55	0.40		
M	0.085	0.150	0.110		
а	8°				
All Dimensions in mm					

## **Suggested Pad Layout**

Please see AP02001 at http://www.diodes.com/datasheets/ap02001.pdf for the latest version.



Dimensions	Value (in mm)		
Z	2.9		
X	0.8		
Υ	0.9		
С	2.0		
E	1.35		





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